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ΡΛΝ	JIT
	SEMI
	CONDUCTOR

#### 20V P-Channel Enhancement Mode MOSFET

Current

#### **Features**

Voltage

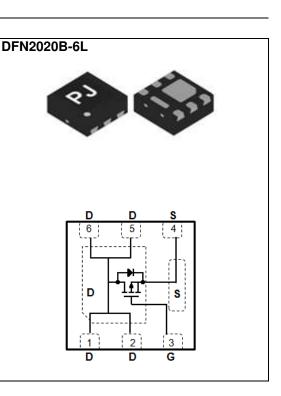
• RDS(ON) , VGS@-4.5V, ID@-7.2A<32mΩ

-20 V

- Rds(on) , Vgs@-2.5V, Id@-5.0A<39m $\Omega$
- RDS(ON) , VGS@-1.8V, ID@-2.5A<48mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : DFN2020B-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0086 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

-7.2A

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 8	V	
Continuous Drain Current		lь	-7.2	А
Pulsed Drain Current		I <sub>DM</sub>	-28.8	А
Power Dissipation	T <sub>a</sub> =25°C	PD	2.8	w
	Derate above 25°C		22	mW/°C
Operating Junction and Storage Temperature Range		TJ,Tsтg	-55~150	°C
Typical Thermal Resistance - Junction to Ambient, t<10s (Note 3)		R <sub>0JA</sub>	44.6	°C/W



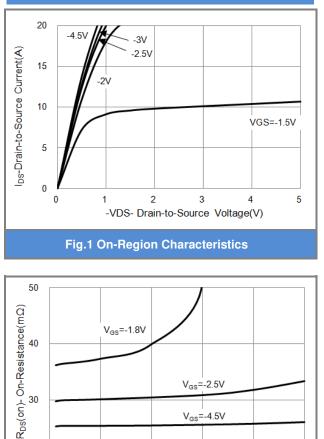
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.35	-0.6	-0.9	V
Drain-Source On-State Resistance		$V_{GS}=-4.5V, I_{D}=-7.2A$	-	25	32	mΩ
	R <sub>DS(on)</sub>	$V_{GS}$ =-2.5V,I <sub>D</sub> =-5.0A	-	30	39	
		V <sub>GS</sub> =-1.8V,I <sub>D</sub> =-2.5A	-	35	48	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-16V,V <sub>GS</sub> =0V	-	-0.01	-1.0	uA
Gate-Source Leakage Current	lgss	V <sub>GS=<u>+</u>8V,V<sub>DS</sub>=0V</sub>	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic (Note 6)	_					
Total Gate Charge	Qg		-	18.9	-	nC
Gate-Source Charge	Qgs	$\label{eq:VDS} \begin{split} V_{\text{DS}} = -10V, \ I_{\text{D}} = -7.2A, \\ V_{\text{GS}} = -4.5V \ ^{(\text{Note } 1,2)} \end{split}$	-	2.8	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	4.2	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1785	-	pF
Output Capacitance	Coss		-	152	-	
Reverse Transfer Capacitance	Crss		-	125	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	12	-	
Turn-On Rise Time	tr	V <sub>DS</sub> =-10V, I <sub>D</sub> =-7.2A, V <sub>GEN</sub> =-4.5V, R <sub>L</sub> =10Ω	-	68	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	82	-	
Turn-Off Fall Time	tf	$R_G=6\Omega$ (Note 1,2)	-	35	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-1.5	A
Diode Forward Voltage	V <sub>SD</sub>	Is=-1A, V <sub>GS</sub> =0V	-	-0.64	-1.2	V

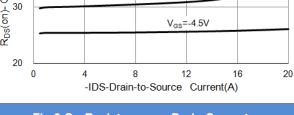
NOTES :

- 1. Pulse width <300us, Duty cycle <2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. R<sub>®JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

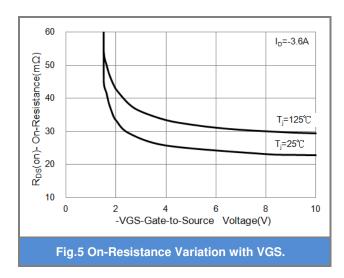


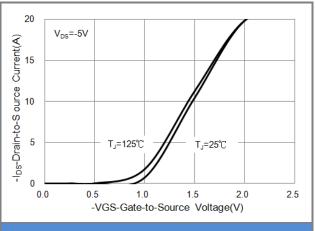


**TYPICAL CHARACTERISTIC CURVES** 



#### Fig.3 On-Resistance vs. Drain Current







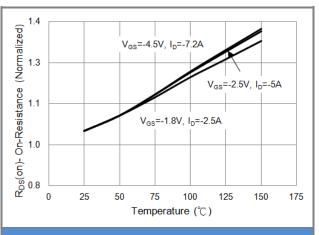
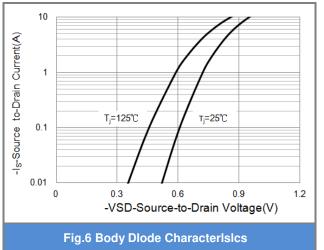
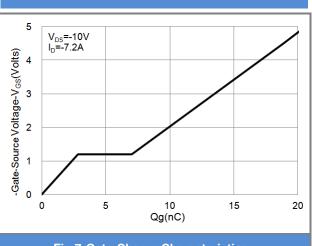


Fig.4 On-Resistance vs. Junction temperature







**TYPICAL CHARACTERISTIC CURVES** 

Fig.7 Gate-Charge Characteristics

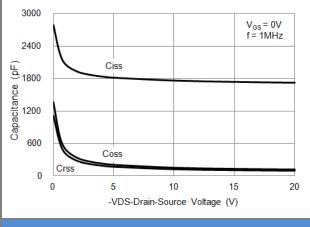


Fig.9 Capacitance vs. Drain-Source Voltage.

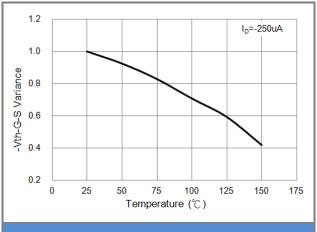


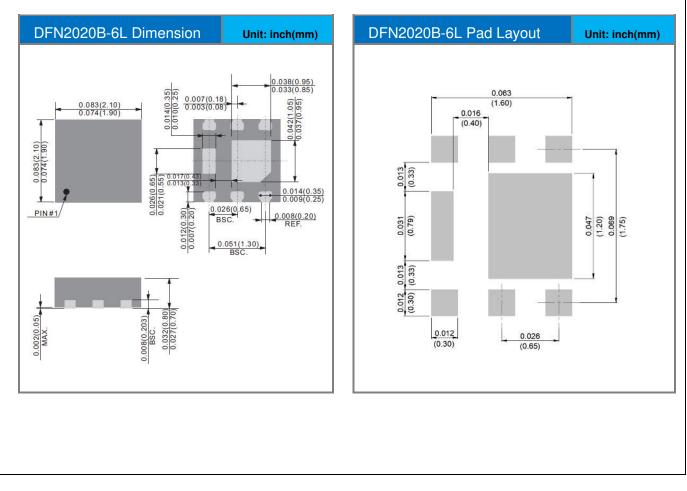
Fig.8 Threshold Voltage Variation with Temperature.



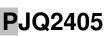
### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ2405_R1_00001	DFN2020B-6L	3K pcs / 7" reel	405	Halogen free RoHS compliant

## Packaging Information & Mounting Pad Layout







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